



Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	1.5Ω @ V _{GS} = 4.5V	0.41A
30V	2.0Ω @ V _{GS} = 2.5V	0.35A
	3.0Ω @ V _{GS} = 1.8V	0.29A
	4.5Ω @ V _{GS} = 1.5V	0.23A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

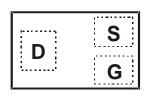
X2-DFN0604-3

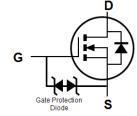




Top View

Bottom View





Top View Package Pin Configuration

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN31D5UFO-7B	X2-DFN0604-3	10k/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DC = Product Type Marking Code

Top View Bar Denotes Gate and Source Side 30V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low Package Profile
- 0.6mm × 0.4mm Package Footprint
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: X2-DFN0604-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208⁽⁴⁾
- Weight: 0.001 grams (Approximate)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	30	V		
Gate-Source Voltage			Vgss	±12	V
Continuous Drain Current (Note 5) $V_{GS} = 4.5V$	Steady State	T _A = +25°C T _A = +85°C	lD	0.41 0.32	А
Pulsed Drain Current (Note 6)			I _{DM}	0.7	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	Steady State	PD	0.38	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	332	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	30	_	—	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS			100	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	Igss	_		±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)					•	·	
Gate Threshold Voltage	V _{GS(TH)}	0.4		1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	1.2	1.5	Ω	V _{GS} = 4.5V, I _D = 100mA	
Static Drain-Source On-Resistance	P	_	1.4	2.0		V _{GS} = 2.5V, I _D = 50mA	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.6	3.0		$V_{GS} = 1.8V, I_D = 20mA$	
			1.8	4.5		V _{GS} = 1.5V, I _D = 10mA	
Diode Forward Voltage	Vsd	_	0.6	1.0	V	V _{GS} = 0V, I _S = 10mA	
DYNAMIC CHARACTERISTICS (Note 8)					•	·	
Input Capacitance	Ciss	_	22.6	_	pF		
Output Capacitance	Coss	_	2.68	—	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	1.8	—	pF		
Total Gate Charge	Qg	_	0.38	—	nC		
Gate-Source Charge	Qgs	_	0.05	—	nC	VGS = 4.5V, VDS = 15V, - ID = 200mA	
Gate-Drain Charge	Qgd	_	0.07		nC		
Turn-On Delay Time	td(ON)	_	3.2		ns		
Turn-On Rise Time	tR		2.2		ns	V _{DD} = 15V, V _{GS} = 4.5V,	
Turn-Off Delay Time	t _{D(OFF)}		21		ns	$R_{G} = 2\Omega, I_{D} = 200 \text{mA}$	
Turn-Off Fall Time	tF	_	7.5	—	ns	1	

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

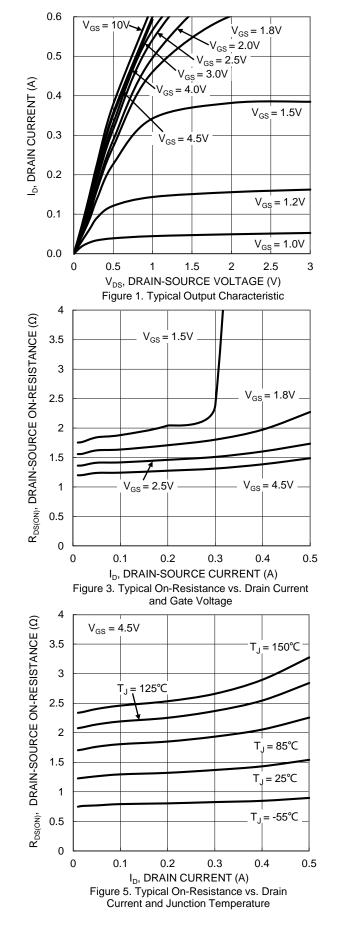
6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

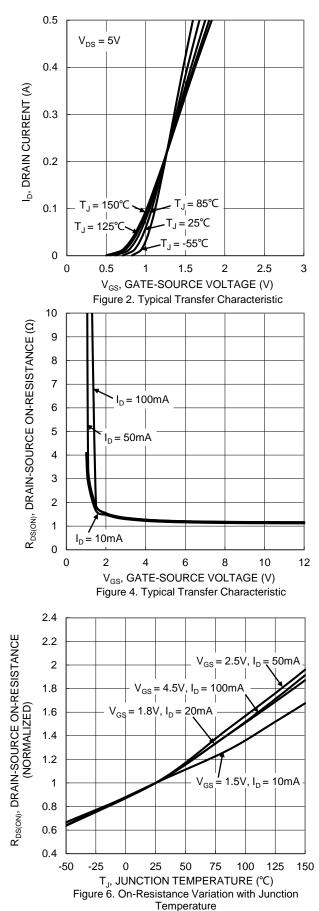
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

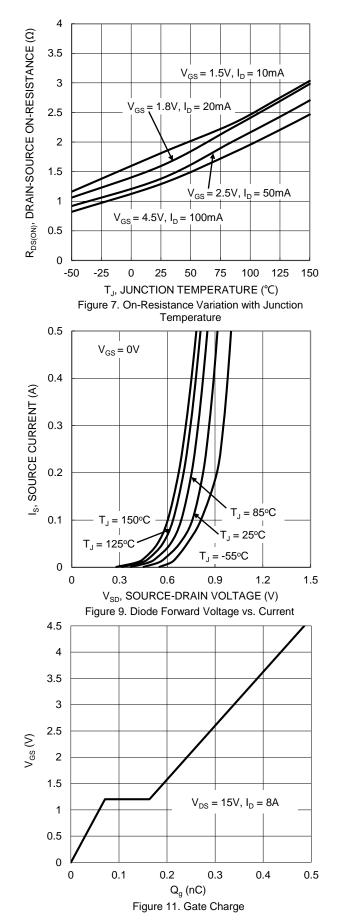


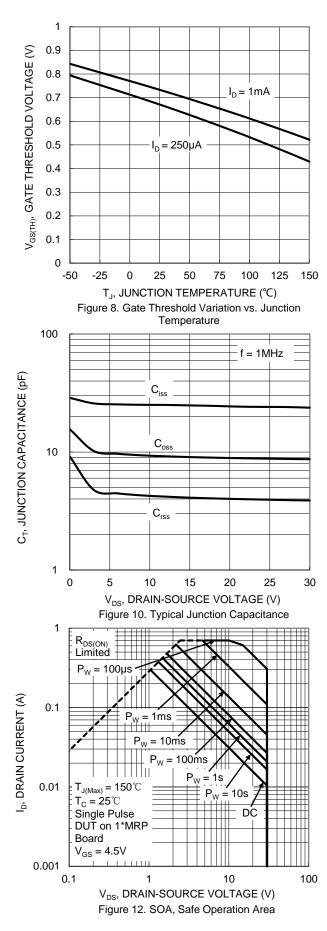
DMN31D5UFO





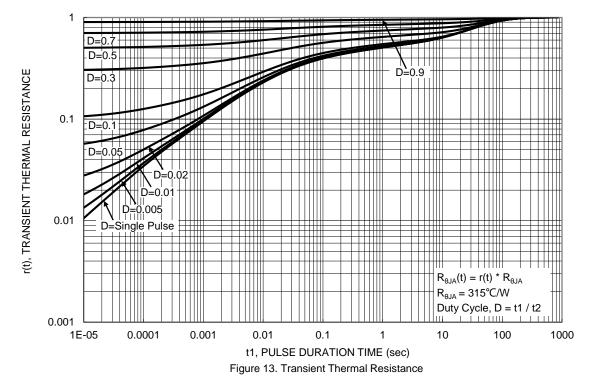






DMN31D5UFO Document number: DS41896 Rev. 3 - 2



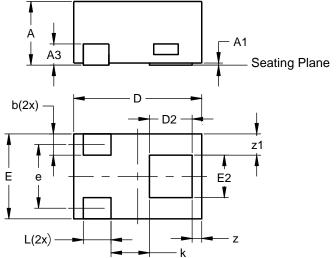




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

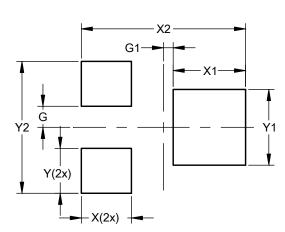
X2-DFN0604-3



		10004.0			
	X2-DFN0604-3				
Dim	Min	Max	Тур		
Α		0.40	0.36		
A1	0.00	0.03	0.02		
A3			0.10		
b	0.07	0.15	0.10		
D	0.55	0.65	0.60		
D2	0.15	0.25	0.20		
Е	0.35	0.45	0.40		
E2	0.15	0.25	0.20		
е			0.30		
k	0.15				
L	0.10	0.18	0.13		
z			0.045		
z1			0.10		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions Value (in mm)

X2-DFN0604-3

G	0.075
G1	0.035
Х	0.180
X1	0.260
X2	0.590
Y	0.160
Y1	0.270
Y2	0.470

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